

# **B140HB**

# SURFACE MOUNT SCHOTTKY BARRIER DIODES

# VOLTAGE RANGE: 40V CURRENT: 1.0 A

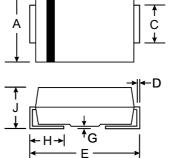
#### Features

- Ultra-low Leakage Current
- Guard Ring Die Construction for
- Transient Protection
  Ideally Suited for Autom
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- Plastic Material: UL Flammability Classification Rating 94V-0

## **Mechanical Data**

- Case: SMB/DO-214AA, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.093 grams (approx.)





В

SMB(DO-214AA)			
Dim	Min	Max	
Α	3.30	3.94	
в	4.06	4.70	
С	1.91	2.21	
D	0.15	0.31	
Е	5.00	5.59	
G	0.10	0.20	
н	0.76	1.52	
J	2.00	2.62	
All Dimensions in mm			

## Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	B140HB	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage @ k = 0.1mA	V <sub>RRM</sub> V <sub>RWM</sub> VR	40	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	28	V
Average Rectified Output Current @ T <sub>T</sub> = 115°C	Ι <sub>Ο</sub>	1.0	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load	IFSM	45	А
Non-Repetitive Peak Forward Surge Current 5µs Single half sine-wave	I <sub>FSM</sub>	430	А
$ \begin{array}{lll} \mbox{Forward Voltage} & @ \ I_F = 1.0A, \ @ \ T_j = \ 25^\circ C \\ & @ \ I_F = 2.0A, \ @ \ T_j = \ 25^\circ C \\ & @ \ I_F = 1.0A, \ @ \ T_j = \ 125^\circ C \\ & @ \ I_F = 2.0A, \ @ \ T_j = \ 125^\circ C \\ & @ \ I_F = 2.0A, \ @ \ T_j = \ 125^\circ C \\ \end{array} $	V <sub>FM</sub>	0.53 0.70 0.49 0.64	V
at Rated DC Blocking Voltage $A = 25^{\circ}C$ $T_A = 125^{\circ}C$	IRM	0.1 4.0	mA
Typical Junction Capacitance (Note 2)	Cj	80	pF
Max. Voltage Rate of Change @ Rated VR	dv/dt	5300	V/µs
Typical Thermal Resistance Junction to Terminal (Note 1)	R <sub>0JT</sub>	36	K/W
Operating and Storage Temperature Range	T <sub>j,</sub> T <sub>STG</sub>	-55 to +150	°C

Notes: 1. Thermal Resistance: Junction to terminal, unit mounted on PC board with 5.0 mm<sup>2</sup> (0.013 mm thick) copper pads as heat sink. 2. Measured at 1.0MHz and applied reverse voltage of 5.0V DC.



